



S1AAF THRU S1MAF

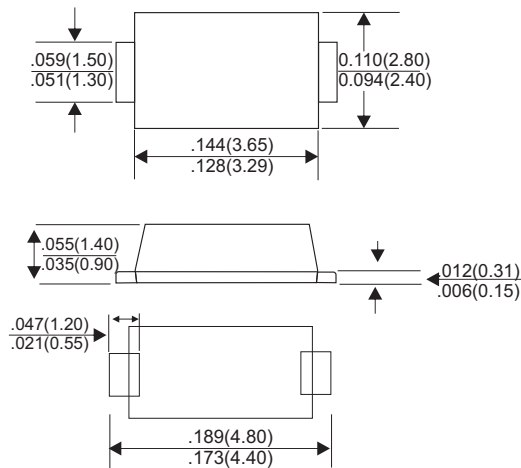
SURFACE MOUNT GENERAL PURPOSE SILICON RECTIFIERS

Reverse Voltage - 50 to 1000 Volts Forward Current - 1.0 Ampere

FEATURES

- * Glass passivate device
- * Ideal for surface mounted applications
- * Low reverse leakage
- * Metallurgically bonded construction
- * High temperature soldering guaranteed:
250°C/10 seconds 0.375"(9.5mm) lead length,
5 lbs.(2.3kg) tension

SMAF



Dimensions in inches and (millimeters)

MECHANICAL DATA

- * Case: JEDEC SMAF molded plastic
- * Terminals: Plated axial leads, solderable per MIL-STD-750, Method 2026
- * Polarity: Color band denotes cathode end
- * Mounting Position: Any
- * Weight: 0.063 grams

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating 25°C ambient temperature unless otherwise specified.
Single phase half wave, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

TYPE NUMBER	S1AAF	S1BAF	S1DAF	S1GAF	S1JAF	S1KAF	S1MAF	UNITS	
Maximum Recurrent Peak Reverse Voltage	50	100	200	400	600	800	1000	V	
Maximum RMS Voltage	35	70	140	280	420	560	700	V	
Maximum DC Blocking Voltage	50	100	200	400	600	800	1000	V	
Maximum Average Forward Rectified Current .375"(9.5mm) Lead Length at Ta=75°C								1.0	A
Peak Forward Surge Current, 8.3 ms single half sine-wave superimposed on rated load (JEDEC method)								30	A
Maximum Instantaneous Forward Voltage at 1.0A								1.1	V
Maximum DC Reverse Current Ta=25°C								5.0	μA
at Rated DC Blocking Voltage Ta=100°C								50	μA
Typical Junction Capacitance (Note 1)								15	pF
Typical Thermal Resistance RθJA (Note 2)								50	°C/W
Operating and Storage Temperature Range Tj, Tstg								-65 — +175	°C
Marking Code	S1A	S1B	S1D	S1G	S1J	S1K	S1M		

NOTES:

1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.
2. Thermal Resistance from Junction to Ambient.

RATING AND CHARACTERISTIC CURVES (S1ASF THRU S1MAF)

FIG.1-TYPICAL FORWARD CHARACTERISTICS

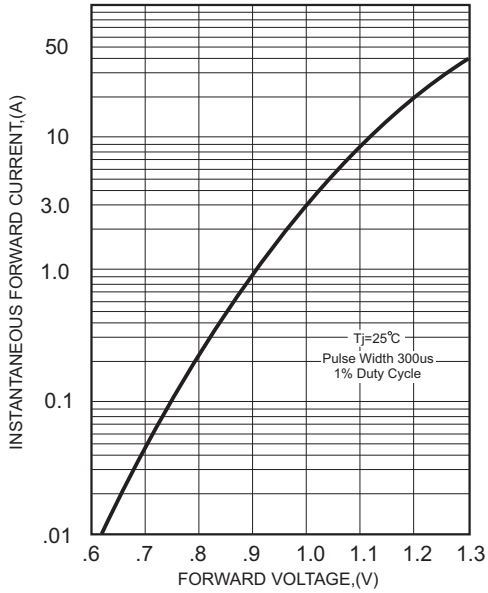


FIG.2-TYPICAL FORWARD CURRENT DERATING CURVE

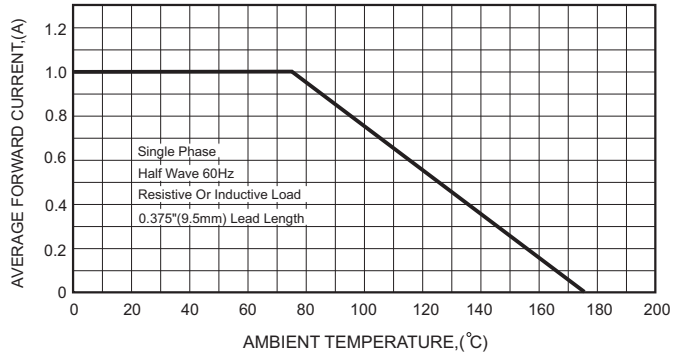


FIG.4-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

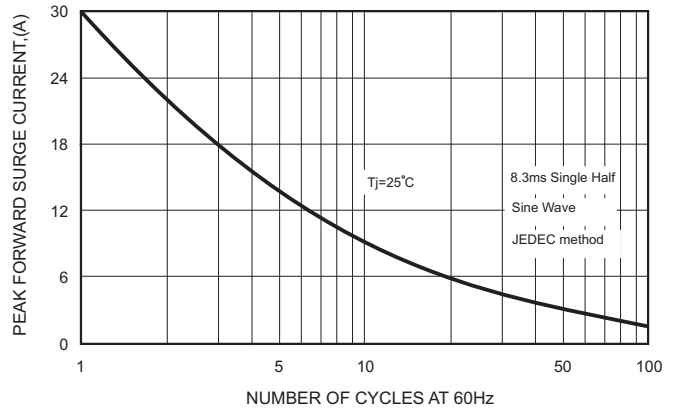


FIG.3 - TYPICAL REVERSE CHARACTERISTICS

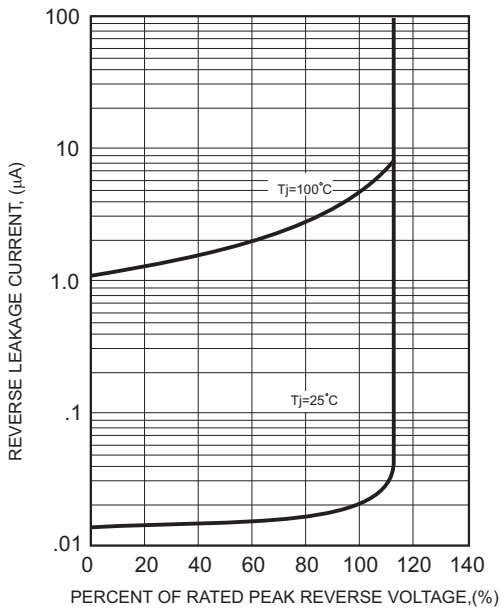


FIG.5-TYPICAL JUNCTION CAPACITANCE

